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Polaron with disordered electron-phonon interaction

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A single electron in one dimensional lattice is considered within the framework of extended Holstein model at strong-coupling limit. Disordered density-displacement type electron-phonon interaction is proposed. Basic parameters of small polaron formed due to disordered electron-phonon interaction are calculated. It is shown that disordered electron-phonon interaction substantially influences all properties of the polaron. Depending on disordered electron-phonon interaction polaronic effect might be enhanced or diminished. It turns out that all parameters of the polaron are site dependent. Further application of proposed model is briefly discussed.

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I. INTRODUCTION

Polaron concept was introduced in the 30^{th} years of XX century by Landau [1] and later was theoretically developed by a number of researchers (see review [2]). Though in the field of polaron physics there are substantial understanding of main features of polaron related phenomena in a variety of solids, there still remain an open issues to be clarified. One of them is the application of the theoretical models to the real solids, in particular the various disordered systems. An interplay of lattice disorder and electron-phonon interaction in such systems, as it is well known, determines charge carrier dynamics. In the past decades Holstein polarons [3] were studied in a variety of medium, including near an impurity [4–6] and in a disordered lattice [7–13]. The all above mentioned works except of Ref.[4] deal with local electron-phonon interaction, in which charge carrier interacts only with onsite intramolecular vibrations. In reality, charge carrier interacts simultaneously with all ions of the lattice and the range of this electron-phonon interaction extends over many lattice units. At the same time disorder influences coupled electron-phonon system too. Noteworthy that in work [6] it was shown opposite effect namely that electron-phonon interaction renormalizes disorder potential and that disorder seen by a polaron is different from the bare disorder[12]. In this sense, an electron sees the disordered ions and as a consequence it interacts with them via electron-phonon interaction which is spatially disordered as well. Such type of disordered electron-phonon interaction and its role in polaron formation was not studied yet. The objective of this paper is to remedy this shortcoming. In order to do this we further develop an idea of Ref.[14] with regard of polarons and apply it to disordered lattice.

Namely in Ref.[14] a model of a polaron with a long-range "density-displacement" type force was introduced. The model by itself represents an extension of the Fröhlich polaron model [15] to a discrete ionic crystal lattice or extension of the Holstein polaron model [3] to a case when an electron interacts with many ions of a lattice with longer ranged electron-phonon interaction. Subsequently, the model was named as the extended Holstein model (EHM) [16]. The model was introduced in order to mimic $high-T_c$ cuprates, where the in-plane (CuO_2) carriers are strongly coupled to the c-axis polarized vibrations of the *apical* oxygen ions [17]. In the last decades the model was studied in great detail in Refs.[16, 18–39].

II. THE MODEL

In this paper we deal with the extended Holstein model in one dimensional lattice in which electron-phonon interaction is disordered. The Hamiltonian of the model is [14]

$$H = H_e + H_{ph} + H_{e-ph} \tag{1}$$

where

$$H_e = -t\sum_{\mathbf{n}}(c^{\dagger}_{\mathbf{n}}c_{\mathbf{n+a}} + H.c.) \tag{2}$$

is the electron hopping energy,

$$H_{ph} = \sum_{\mathbf{m}}\left(-\frac{\hbar^2\partial^2}{2M\partial u^2_{\mathbf{m}}} + \frac{M\omega^2 u^2_{\mathbf{m}}}{2}\right) \tag{3}$$

is the Hamiltonian of the vibrating ions,

$$H_{e-ph} = \sum_{\mathbf{n},\mathbf{m}} f_{\mathbf{m}}(\mathbf{n})\cdot u_{\mathbf{m}}c^{\dagger}_{\mathbf{n}}c_{\mathbf{n}} \tag{4}$$

describes interaction between the electron that belongs to a lower chain and the ions of an upper chain (see below). Here t is the nearest neighbor hopping integral, $c^{\dagger}_{\mathbf{n}}(c_{\mathbf{n}})$ is a creation (destruction) operator of an electron on a cite $\mathbf{n}$, $u_{\mathbf{m}}$ is the c- polarized displacement of the $\mathbf{m}$-th ion and $f_{\mathbf{m}}(\mathbf{n})$ is an interacting density-displacement type force between an electron on a site $\mathbf{n}$ and the c-polarized vibration of the $\mathbf{m}$-th ion. M is the mass of the vibrating ions and ω is their frequency.

We consider an electron performing hopping motion on a lower chain consisting of the static sites, but interacting with all ions of an upper chain via a long-range

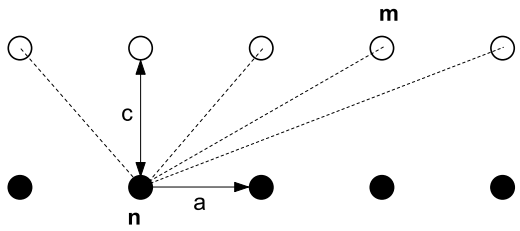

FIG. 1: An electron hops on a lower chain and interacts with the ions vibrations of an upper infinite chain via a density-displacement type force $f_{\mathbf{m}}(\mathbf{n})$. The distances between the chains ($|\mathbf{c}|$) and between the ions ($|\mathbf{a}|$) are assumed equal to 1. Dotted lines represent the interaction of an electron on site $\mathbf{n}$ with the ions of the upper chain.

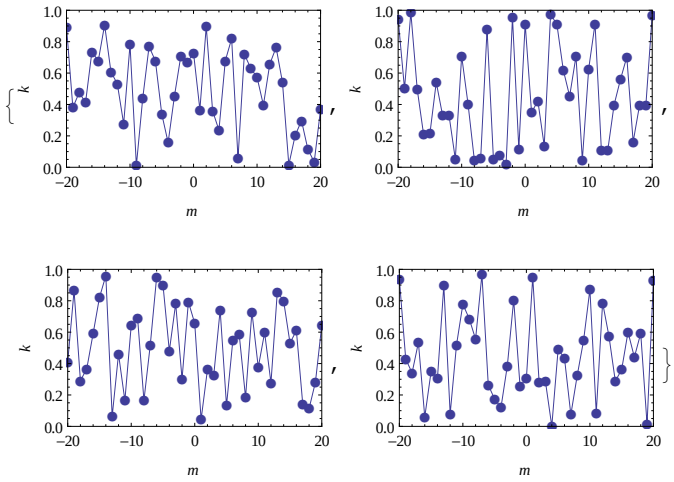

FIG. 2: The value of k at m for different types of disorder of upper chain's ions. k is taken as uniformly distributed randomized number in the interval (0,1).

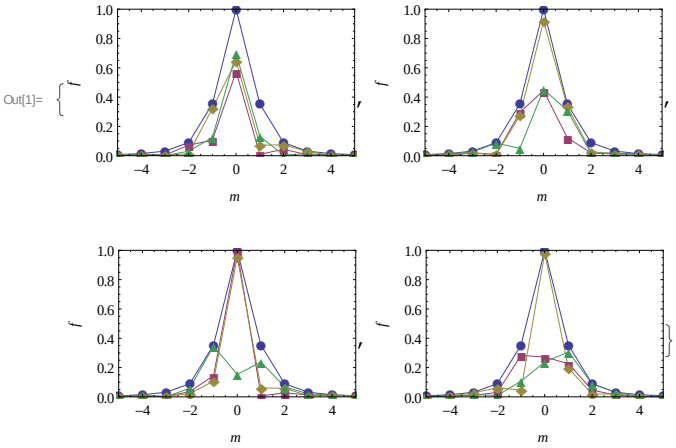

FIG. 3: Dependence of *disordered* density-displacement type electron-phonon interaction force $f_{\mathbf{m}}(\mathbf{0})$ on $\mathbf{m}$ for different types of disorder of upper chain.

density-displacement type force, as shown in Fig.1. So, the motion of an electron is always one-dimensional, but a vibration of the upper chain's ions is c- polarized (perpendicular to the chains). There is no doubt that an explicit analytical form of the force $f_{\mathbf{m}}(\mathbf{n})$ is one of crucial aspects determining polaron parameters. Of cause, it depends on structural elements that located on sites $\mathbf{m}$. Whether the structural elements are neutral, charged (positively or negatively) or dipoles (electrical or magnet) this force may have different origin and may lead to different polaronic states. As in Refs.[19, 29, 31, 34] here it is also assumed that the structural elements are electrically charged (positive or negative) and thus the force has Coulombic nature. Now let's try to simulate a disorder in the lattice. There are many ways to simulate a disorder in the lattice. One of them is allocation driven disorder where positions of upper chain's ions are randomized. Of course, if allocation of the ions throughout the upper chain is disordered then density-displacement type force $f_{\mathbf{m}}(\mathbf{n})$ is also disordered. An another way to simulate a disorder in the lattice is randomize the charge value of the upper chain's ions. There are a lot of examples for the systems where such type of charge fluctuations or modulations occurs (see for example [40–42]). Modulations of charge states of structural elements of the lattice may occur in many other systems like cuprates, manganites, organic semiconductors and it has become possible owing to modern crystal growth technology. Here we consider only charge modulation (fluctuation) driven disorder of electron-phonon interaction and its consequences in polaron formation. So, our consideration is relevant to all compounds where polaron formation is possible and it occurs in the presence of charge modulation's (fluctuation) driven electron-phonon interaction.

Considering the above said opinions without loss of generality one writes explicitly a discrete form of the density-displacement type electron-phonon interaction force as:

$$f_{\mathbf{m}}(\mathbf{n}) = \frac{c \cdot \kappa_{\mathbf{m}}}{(|\mathbf{n}-\mathbf{m}|^2 + c^2)^{3/2}} \tag{5}$$

where $\kappa_{\mathbf{m}}$ is some force coefficient, which characterizes charge states of the upper chain's ions, and $|\mathbf{n}-\mathbf{m}|$ is measured in units of $|\mathbf{a}|$. In this work we choose $\kappa_{\mathbf{m}}$ as uniformly distributed random number in the interval of $(0,1)$, so $\kappa_{\mathbf{m}} \neq \kappa_{\mathbf{m}'}$ and $\kappa_{\mathbf{m}} \in (0,1)$. For this reason the value of $\kappa_{\mathbf{m}}$ changes randomly in passing $\mathbf{m}$ from one site to another site.

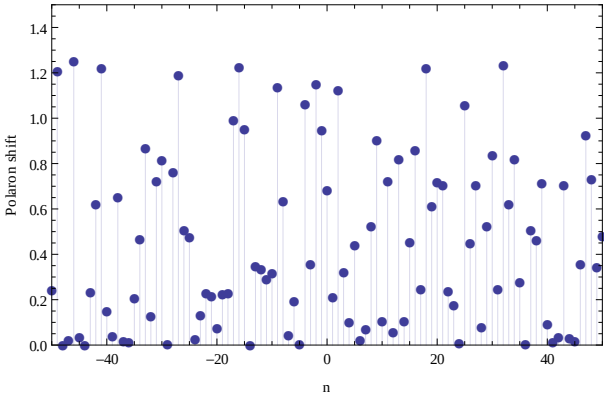

FIG. 4: The value of polaron shift E_P at sites $\mathbf{n}$ due to disordered electron-phonon interaction.

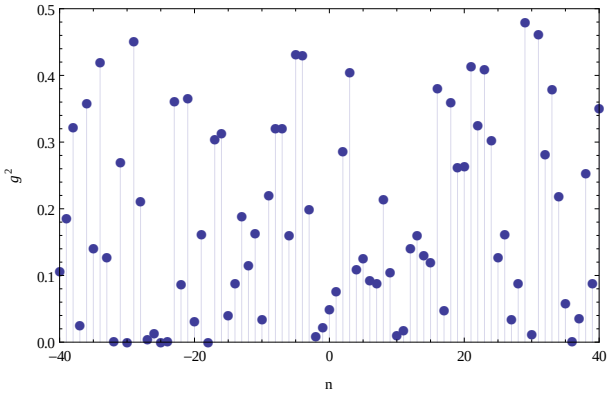

FIG. 5: The value of band-narrowing factor g^2 at sites $\mathbf{n}$ due to disordered electron-phonon interaction.

III. RESULTS AND DISCUSSION

The possible ways of changing of the value of $k_{\mathbf{m}}$ are illustrated in Fig.2. In turn density-displacement force Eq.(5) acquires a peculiarity of randomized (i.e. disordered) electron-phonon interaction force. From now the force Eq.(5) has two features: (i) it is still longer-ranged and descends as r^{-3}, where r- is the distance between the electron and ion under consideration, and (ii) it is randomized (disordered). In Fig.3 the plots of the dependence of the value of density-displacement electron-phonon interaction force Eq.(5) on site indexes $\mathbf{m}$ are presented [45]. As it is seen from the plots randomization of the electron-phonon interaction force changes the picture of the phenomenon drastically (qualitatively and quantitatively). Indeed, for a regular lattice we have $f_{|\mathbf{m}|}(\mathbf{n}) > f_{|\mathbf{m}'|}(\mathbf{n})$ if $|\mathbf{m}| < |\mathbf{m}'|$. But for our case of the lattice with the disordered electron-phonon interaction the above relation is not always true i.e. on some sites $f_{|\mathbf{m}|}(\mathbf{n}) < f_{|\mathbf{m}'|}(\mathbf{n})$ even if $|\mathbf{m}| < |\mathbf{m}'|$. This is the effect of considering disorder on the density-displacement type electron-phonon interaction. As a result of all parameters of the polaron will be affected by the disorder. In order to show this explicitly we calculate just some basic polaron's parameters like E_p- polaron shift, g^2- band-narrowing factor, γ- a numerical factor that depends on crystal struture and binds the polaron energy E_p to band-narrowing factor g^2 via relation $g^2 = \gamma E_p/\hbar\omega$ and $\Phi(\mathbf{n}-\mathbf{n}')$- whose gradient in corresponding direction is important to determine the mass of the polaron in a regular lattice.

In strong electron-phonon coupling limit and nonadiabatic regime one uses the standard procedures such as Lang-Firsov transformation [43] that eliminates electron-phonon interaction term (4). Subsequent use of perturbation expansion of the transformed Hamiltonian H_e with respect to parameter $\lambda^{-1} = 2t/E_p$ up to the first order in the hopping integral yields

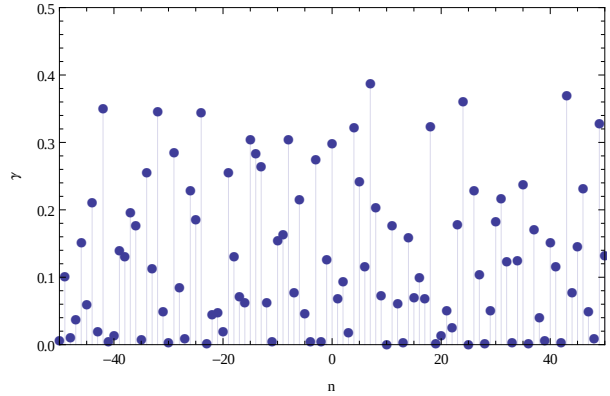

FIG. 6: The value of γ at sites $\mathbf{n}$ due to disordered electron-phonon interaction.

$$E_p(\mathbf{n}) = \frac{1}{2M\omega^2}\sum_{\mathbf{m}} f^2_{\mathbf{m}}(\mathbf{n}), \tag{6}$$

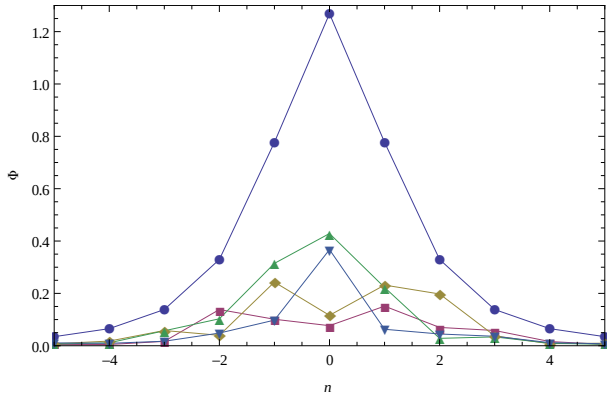

FIG. 7: The value of $\Phi(\mathbf{n})$ at sites $\mathbf{n}$ due to disordered electron-phonon interaction.

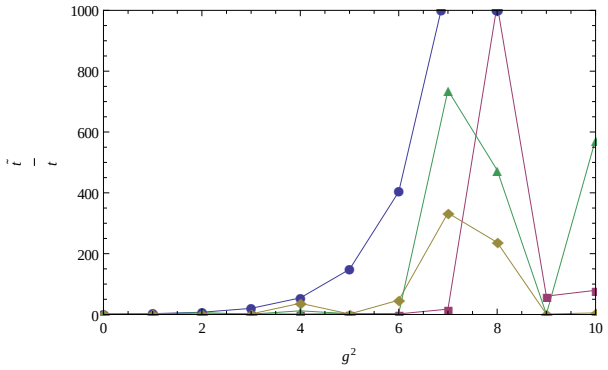

FIG. 8: The value of renormalized hopping integral versus g^2 calculated taking into account disordered character of electron-phonon interaction.

$$g^2(\mathbf{n},\mathbf{a}) = \frac{1}{2M\hbar\omega^3}\sum_{\mathbf{m}}[f^2_{\mathbf{m}}(\mathbf{n}) - f_{\mathbf{m}}(\mathbf{n})f_{\mathbf{m}}(\mathbf{n}+\mathbf{a})], \quad (7)$$

$$\gamma(\mathbf{n},\mathbf{a}) = 1 - \frac{\sum_{\mathbf{m}} f_{\mathbf{m}}(\mathbf{n})\cdot f_{\mathbf{m}}(\mathbf{n}+\mathbf{a})}{\sum_{\mathbf{m}} f^2_{\mathbf{m}}(\mathbf{n})}, \quad (8)$$

and

$$\Phi(\mathbf{n}-\mathbf{n}') = \sum_{\mathbf{m}} f_{\mathbf{m}}(\mathbf{n})\cdot f_{\mathbf{m}}(\mathbf{n}') \quad (9)$$

Though these parameters were obtained by perturbation theory under certain assumptions we accept them as starting point expressions for the discussion of the influence of disordered electron-phonon interaction on polaron's parameters. In Fig.4, Fig.5 and Fig.6 we presented the plots of values of $E_p(\mathbf{n})$, $g^2(\mathbf{n},\mathbf{a})$ and $\gamma(\mathbf{n},\mathbf{a})$, respectively, on different sites $\mathbf{n}$. As it is seen from the presented date all these parameters are randomized too. Depending on disordered electron-phonon interaction polaronic effect might be enhanced or diminished. The values of $\Phi(\mathbf{n})$ on different sites $\mathbf{n}$ are given in Fig.7. Randomization undergoes also polaron's hopping integral from one site to on another site of the lattice. Within the used framework one can estimate the value of hopping integral from ratio $\tilde{t}/t \simeq \exp(g^2)$ and plot its values for different disorders, Fig.8. One can observe the same tendency for hopping integral. Findings indicate that disorder changes a picture of polaron formation, and it is appears that all polaron's parameters are site dependent i.e disordered. Something similar ideas, namely about site dependence of polaron energy (shift) and local electron-phonon interaction's coupling constant on $\mathbf{n}$, can be found in [44].

The above results were obtained under assumption that the values of κ are uniformly distributed within the interval (0,1). But our model can be straightforwardly generalized to the case when the values of κ belong to an arbitrary interval (p,q) and is defined within it by some function of distribution (Gaussian, Poisson, Bernoulli and so on). There are a great variety of options for simulation here. In our model it is also possible to simulate string like structures and study a polaron formation in such structures. For this purpose it is sufficient to select a required set of values of $\kappa_{\mathbf{m}}$, for example $\kappa_{\mathbf{m}} = (\ldots,0,0,1,1,1,1,0,0,1,1,1,1,\ldots)$. There are also other possibilities.

Another question that we would like to discuss here concerns the size of the polaron in the lattice where electron-phonon interaction is disordered. As for the Hamiltonian (1) there are two points of view on this matter. Ref.[14] treats the polaron of the model (1) as *small* Fröhlich polaron, while Ref.[16] treats the polaron of the model (1) as *large* Holstein polaron. Here we follow the definition in which small polaron is formed at $t/E_p \ll 1$ and large polaron is formed at $t/E_p \gg 1$ [44]. Since in our model the ratio t/E_p fluctuates from site to site one can not say clearly about size of polaron even it formed by long-rang electron-phonon interaction (5). For some sites the condition of small (large) polaron formation is satisfied, while for other sites it is ruled out. Then one may say that in the systems with disordered electron-phonon interaction polaron's size also modulated by the disordered electron-phonon interaction. It seems that such property of polarons in disordered structures is common since in Ref.[5] a mixed behavior typical for large (away impurity) and small (near impurity) polarons was also expected for a crystal with impurities. The results obtained here suggest further study of polaron formation in disordered structures taking into an account not only on-diagonal and off-diagonal aspects of the disorder, but also the disordered nature of the electron-phonon interaction as well.

IV. CONCLUSION

In conclusion we have studied one dimensional lattice within the framework of the extended Holstein model. Considering the case when charge fluctuations can occur in the system we have applied the extended Holstein model to study polaron formation in the system. In doing this we introduce a disordered density-displacement type electron-phonon interaction by randomizing force constant that describes charge state of the ions. We have calculated the basic parameters of polaron with the disordered electron-phonon interaction and have found that all parameters of polaron are drastically affected by the disordered electron-phonon interaction. It turns out that all parameters of polaron are site dependent. This is true with respect to ratio t/E_p that determines a polaron size. Then one can not say definitely about size of polaron in such system. The size of the polaron depends on its position and from the disorder seen by polaron from this location. So, the size of the polaron is modulated (disordered) i.e. site dependent in the system with disordered electron-phonon interaction.

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[1] L.D.Landau, Physikalische Zeitschrift der Sowjetunion. **3**, 664 (1933).
[2] Alexandre S. Alexandrov and Jozef T. Devreese, *Advances in Polaron Physics* (Springer, 2009).
[3] T.Holstein, Ann. Phys. **8**, 325 (1959); *ibid* **8**, 343 (1959).
[4] J.P.Hague, P.E.Kornilovitch, and A.S.Alexandrov, Phys. Rev. B, **78**, 092302 (2008).
[5] A.S.Mishchenko, N.Nagaosa, A.Alvermann, H.Fehske, G.De Filippis, V.Cataudella, and O.P.Sushkov, Phys Rev. B **79**, 180301(R) (2009).
[6] Hadi Ebrahimnejad and Mona Berciu, Phys Rev. B **85**, 165117 (2012).
[7] Morrel H.Cohen, E.N.Economou and C.M.Soukoulis, Phys Rev.Lett. **51**, 1202 (1983).
[8] Franz X.Bronold and Holger Fehske, Phys Rev. B **66**, 073102 (2002).
[9] J.Chatterjee and A.N.Das, Eur.Phys.J. B, **46**, 481 (2005).
[10] M.Berciu and G.A.Sawatzky, EuroPhysLett, **81**, 57008 (2008).
[11] M.Berciu, A.S.Mishchenko and N.Nagaosa, EuroPhysLett, **89**, 37007 (2010).
[12] Hadi Ebrahimnejad and Mona Berciu, Phys Rev. B **86**, 205109 (2012).
[13] Oliver Robert Tozer and William Barford, Phys. Rev. B, **89**, 155434 (2014).
[14] A.S.Alexandrov and P.E.Kornilovitch, Phys. Rev. Lett. **82**, 807 (1999).
[15] H.Fröhlich, Adv. Phys. **3**, 325 (1954).
[16] H.Fehske, J.Loos, and G.Wellein, Phys. Rev. B **61**, 8016 (2000).
[17] T.Timusk, C.C.Homes, and W.Reichardt, in Anharmonic Properties of High-TC Cuprates, edited by D.Mihailović et. al. (Wolrd Scientific, Singapore, 1995), p.171
[18] P.E.Kornilovitch, Phys. Rev. Lett., **81**, 5382(1998).
[19] P.E.Kornilovitch, Phys. Rev. B, **59**, 13531(1999).
[20] P.E.Kornilovitch, Phys. Rev. B, **60**, 3237(1999).
[21] J.Bonca and S.A.Trugman, Phys. Rev. B **64**, 094507 (2001).
[22] A.S.Alexandrov, P.E.Kornilovich, Physics. Lett. A **299**, 650 (2002).
[23] A.S.Alexandrov and P.E.Kornilovich, J. Phys.: Condens. Matter. **14**, 5337 (2002).
[24] C.A.Perroni, V.Cataudella, and G. De Filippis, J. Phys.: Condens. Matter **16**, 1593 (2004).
[25] V.Cataudella, G. De Filippis, F.Martone and C.A.Perroni, Phys. Rev. B **70**, 193105 (2004).
[26] Martin Hohenadler, Hans Gerd Evertz, and Wolfgang von der Linden, Phys. Rev. B, **69**, 024301(2004).
[27] A.S.Alexandrov and B.Ya.Yavidov, Phys. Rev. B, **69**, 073101(2004).
[28] V.M.Stojanović, P.A.Bobbert and M.A.J.Michels, Phys. Stat. Sol. C, **1**, 172(2004).
[29] P.E.Spencer, J.H.Samson, P.E.Kornilovitch, and A.S.Alexandrov, Phys. Rev. B, **71**, 184310(2005).
[30] K.D.Meisel, H.Vocks, P.A.Bobbert, Phys. Rev. B, **71**, 205206(2005).
[31] J.P.Hague, P.E.Kornilovitch, A.S.Alexandrov, and J.H.Samson, Phys. Rev. B, **73**, 054303(2006).
[32] P.E.Kornilovitch, J. Phys.: Condens. Matter **19**, 255213 (2007).
[33] J.P.Hague, P.E.Kornilovitch, J.H.Samson, and A.S.Alexandrov, J. Phys.: Condens. Matter **19**, 255214(2007).
[34] J.P.Hague and P.E.Kornilovitch, Phys. Rev. B, **80**, 054301(2009).
[35] B.Ya.Yavidov, Sh.S.Djumanov and S.Dzhumanov, Physics Letters A, **374**, 2772 (2010).
[36] Monodeep Chakraborty, B.I.Min, Atisdipankar Chakrabarti, A.N.Das, Phys. Rev. B, **85**, 245127 (2012).
[37] Monodeep Chakraborty and B.I.Min, Phys. Rev. B, **88**, 024302 (2013).
[38] Ka-Ming Tam, Shan-Wen Tsai and David K. Campbell, Phys. Rev. B, **89**, 014513 (2014).
[39] Monodeep Chakraborty, Masaki Tezuka and B.I.Min, Phys. Rev. B, **89**, 035146 (2014).
[40] A.Ohtomo, D.A.Müller, J.L.Grazul and H.Y.Hwang, Nature, **419**, 378 (2002).
[41] L.-M.Peng, M.Gao, Z.F.Dong, X.L.Dong, B.R.Zhao, and Z.X.Zhao, Phys. Rev. B, **62** 189 (2000).
[42] M.Hashimoto, G.Ghiringhelli, W.-S.Lee, G.Dellea, A.Amorese, C.Mazzoli, K.Kummer, N.B.Brookes, B.Moritz, Y.Yoshida, H.Eisaki, Z.Hussain, T.P.Devereaux, Z.-X.Shen, and L.Braicovich, Phys. Rev. B, **89**, 220511(R) (2014).
[43] I.G.Lang, Yu.A. Firsov, Zh. Eksp. Teor. Fiz. 43 (1962) 1843, Sov. Phys.-JETP 16 (1963) 1301.
[44] Harald Böttger, Valerij V.Bryksin, *Hopping Conduction in Solids* (Academie-Verlag, Berlin, 1985), p. 26
[45] In figures 3, 7 and 8 blue-circle lines correspond to a regular lattice and are given for a comparison.